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| STAT                   | EMENT BY           | APPI | CANT                                   | First Named Inventor   | Wonju Cho |  |  |
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|                                   |                    |    |             | Application Number     |           |  |  |
| INFORMATION DISCLOSURE            |                    |    | SUKE        | Filing Date            |           |  |  |
| STATEMENT BY APPLICANT            |                    |    |             | First Named Inventor   | Wonju Cho |  |  |
|                                   |                    |    | · · · · · · | Art Unit               |           |  |  |
| (use as many sheets as necessary) |                    |    |             | Examiner Name          |           |  |  |
| Sheet                             | 2                  | of | 2           | Attorney Docket Number | 2013P148  |  |  |

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| Application Number 10/749,749 |                   |  |  |  |  |
| Filing Date                   | December 30, 2003 |  |  |  |  |
| First Named Inventor          | Wonju Cho         |  |  |  |  |
| Art Unit                      | 2818              |  |  |  |  |
| Examiner Name                 | Dang, Phuc T      |  |  |  |  |
| Attorney Docket Number        | 2013P148          |  |  |  |  |

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| Attorney Docket Number        | 2013P148          |  |  |  |  |

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| PD                    |                                 | H-H. VUONG, "Design of 25-nm SALVO PMOS Devices," IEEE Electron Device Letters, Vol. 21, No. 5, May 2000, pps. 248-250.   |    |  |  |  |  |
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